

## PACKAGE DIMENSIONS INCH [mm]



ACTIVE AREA $=2.98 \mathrm{~mm}^{2}$

## FEATURES

- 400 nm CWL
- 40 nm FWHM
- Large active area


## DESCRIPTION

The PDB-C440-46B is a silicon, PIN planar diffused, photodiode with a wide band interference filter. The detector filter combination has a wide 40 nm half bandwidth designed for high speed photoconductive applications. Packaged in a TO-46 metal can.

## APPLICATIONS

- Spectrophotometry
- Chemistry instrumentation
- Liquid chromatography


## ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

SPECTRALRESPONSE

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 75 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -20 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{o}}$ | Operating Temperature Range | -15 | +70 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{s}}$ | Soldering Temperature* |  | +240 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max
ELECTRO-OPTICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current** | H = $100 \mathrm{fc}, 2850 \mathrm{~K}$ | 40 | 45 |  | $\mu \mathrm{A}$ |
| 1 D | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 150 | 300 | pA |
| Rsh | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | . 5 | 1.0 |  | G $\Omega$ |
| TC Rsh | Rsp Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | \% / ${ }^{\circ} \mathrm{C}$ |
| CJ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}^{* *}$ |  | 10 |  | pF |
| CWL | Center Wavelength | (CWL, $\lambda$ o) +/- 2 nm |  | 400 |  | nm |
| HBW | Half Bandwidth | (FWHM) |  | 40 |  | nm |
| Vbr | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 70 | 100 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{mV}$ @ Peak |  | $1.5 \times 10^{-14}$ |  | $\mathrm{W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}$ |  | 10 |  | nS |

Information in this technical datasheet is believed to be correctand reliable. However, no responsibility is assumed for possible inaccuracies oromission. Specifications are subject to change withoutnotice. ${ }^{* * f}=1 \mathrm{MHz}$, ${ }^{* * *}$ withoutfilter

